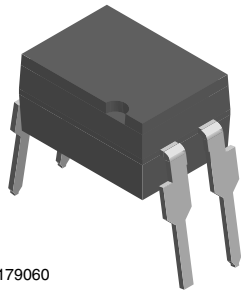
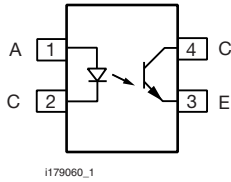




## Optocoupler, Phototransistor Output, High Reliability, 5300 V<sub>RMS</sub>



i179060



### DESCRIPTION

The SFH615XXX features a large assortment of current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm lead spacing. Creepage and clearance distances of > 8 mm are achieved with option 6. This version complies with 60950 (DIN VDE 0805) for reinforced insulation up to operation voltage of 400 V<sub>RMS</sub> or DC.

### FEATURES

- Low CTR degradation
- Good CTR linearity depending on forward current
- Isolation test voltage, 5300 V<sub>RMS</sub>
- High collector emitter voltage, V<sub>CEO</sub> = 70 V
- Low saturation voltage
- Fast switching times
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity (unconnected base)
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

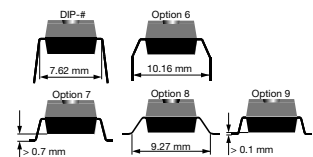
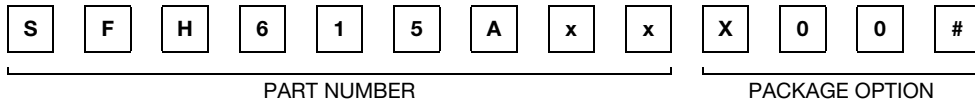


RoHS COMPLIANT

### AGENCY APPROVALS

- UL1577
- cUL
- DIN EN 60747-5-5 (VDE 0884) available with option 1
- BSI

### ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)			
	5 mA			
<b>UL, cUL, BSI, FIMKO</b>	<b>50 to 600</b>	<b>100 to 600</b>	<b>100 to 300</b>	<b>50 to 150</b>
DIP-4	SFH615AA	SFH615AGB	SFH615AGR	SFH615AY
DIP-4, 400 mil, option 6	SFH615AA-X006	-	-	-
SMD-4, option 7	SFH615AA-X007	-	SFH615AGR-X007T	SFH615AY-X007T
SMD-4, option 8	-	-	-	SFH615AY-X008T
SMD-4, option 9	-	SFH615AGB-X009T	-	SFH615AY-X009T <sup>(1)</sup>
<b>UL, cUL, VDE, BSI, FIMKO</b>	<b>50 to 600</b>	<b>100 to 600</b>	<b>100 to 300</b>	<b>50 to 150</b>
DIP-4	SFH615AA-X001	-	SFH615AGR-X001	-
DIP-4, 400 mil, option 6	-	-	SFH615AGR-X016	SFH615AY-X016
SMD-4, option 7	SFH615AA-X017T <sup>(1)</sup>	-	SFH615AGR-X017T <sup>(1)</sup>	-
SMD-4, option 8	-	-	-	SFH615AY-X018T <sup>(1)</sup>
SMD-4, option 9	-	-	-	SFH615AY-X019T <sup>(1)</sup>

### Notes

- Additional options may be possible, please contact sales office
- <sup>(1)</sup> Also available in tubes; do not add T to end



ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
Reverse voltage		V <sub>R</sub>	6	V
DC forward current		I <sub>F</sub>	60	mA
Surge forward current	t <sub>p</sub> ≤ 10 ms	I <sub>FSM</sub>	2.5	A
Power dissipation		P <sub>diss</sub>	100	mW
<b>OUTPUT</b>				
Collector emitter voltage		V <sub>CEO</sub>	70	V
Emitter collector voltage		V <sub>ECO</sub>	7	V
Collector current		I <sub>C</sub>	50	mA
	t <sub>p</sub> ≤ 10 ms	I <sub>C</sub>	100	mA
Total power dissipation		P <sub>diss</sub>	150	mW
<b>COUPLER</b>				
Isolation test voltage between emitter and detector		V <sub>ISO</sub>	5300	V <sub>RMS</sub>
Creepage distance			≥ 7	mm
Clearance distance			≥ 7	mm
Isolation thickness between emitter and detector Comparative tracking index per DIN IEC 112/VDE 0303, part 1		CTI	≥ 175	
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Storage temperature range		T <sub>stg</sub>	-55 to +150	°C
Ambient temperature range		T <sub>amb</sub>	-55 to +100	°C
Soldering temperature <sup>(1)</sup>	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T <sub>slid</sub>	260	°C

**Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- <sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>							
Forward voltage	I <sub>F</sub> = 60 mA		V <sub>F</sub>	-	1.25	1.65	V
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>	-	0.01	10	μA
Capacitance	V <sub>R</sub> = 0 V, f = 1 MHz		C <sub>O</sub>	-	13	-	pF
Thermal resistance			R <sub>thja</sub>	-	750	-	K/W
<b>OUTPUT</b>							
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz		C <sub>CE</sub>	-	5.2	-	pF
Thermal resistance			R <sub>thja</sub>	-	500	-	K/W
Collector emitter saturation voltage	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 2.5 mA		V <sub>CEsat</sub>	-	0.25	0.4	V
Coupling capacitance			C <sub>C</sub>	-	0.4	-	pF
<b>COUPLER</b>							
Collector emitter leakage current	V <sub>CEO</sub> = 10 V	SFH615AA	I <sub>CEO</sub>	-	10	100	nA
		SFH615AGB	I <sub>CEO</sub>	-	10	100	nA
		SFH615AGR	I <sub>CEO</sub>	-	10	100	nA
		SFH615AY	I <sub>CEO</sub>	-	10	100	nA

**Note**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
$I_C/I_F$	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	SFH615AA	CTR	50	-	600	%
		SFH615AGB	CTR	100	-	600	%
		SFH615AGR	CTR	100	-	300	%
		SFH615AY	CTR	50	-	150	%

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Turn-on time	$I_F = 5 \text{ mA}$	$t_{on}$	-	2	-	$\mu\text{s}$	
Turn-off time	$I_F = 5 \text{ mA}$	$t_{off}$	-	25	-	$\mu\text{s}$	

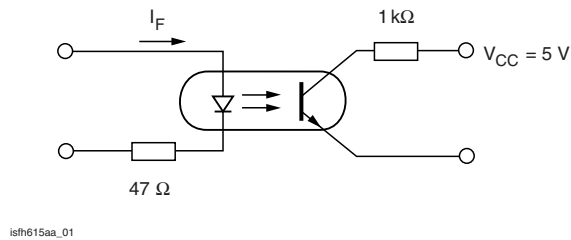
**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified)


Fig. 1 - Switching Operation (with saturation)

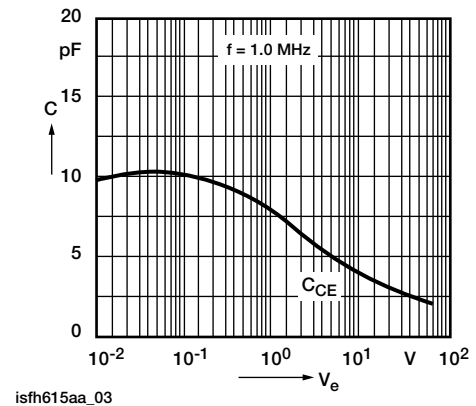


Fig. 3 - Transistor Capacitance (typ.) vs. Collector Emitter Voltage

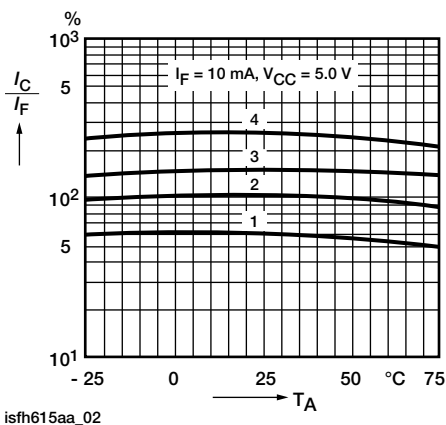


Fig. 2 - Current Transfer Ratio (typ.) vs. Temperature

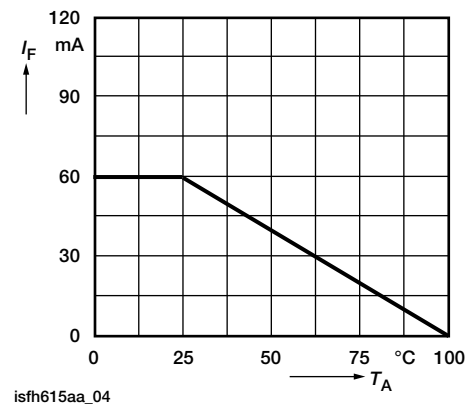


Fig. 4 - Permissible Diode Forward Current vs. Ambient Temperature

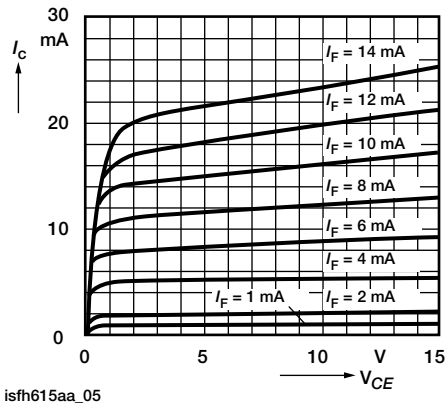


Fig. 5 - Output Characteristics (typ.) Collector Current vs. Collector Emitter Voltage

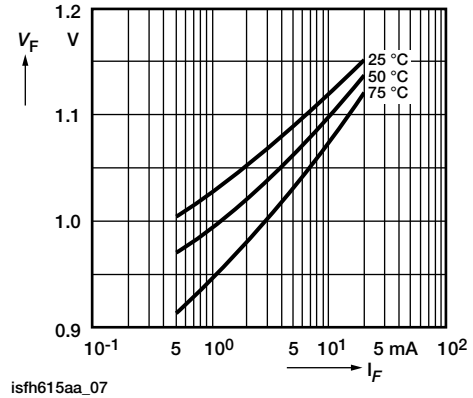


Fig. 7 - Diode Forward Voltage (typ.) vs. Forward Current

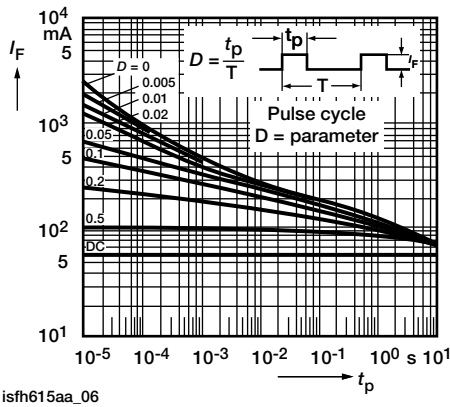


Fig. 6 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

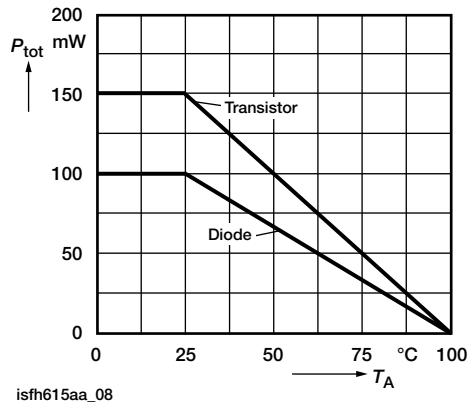
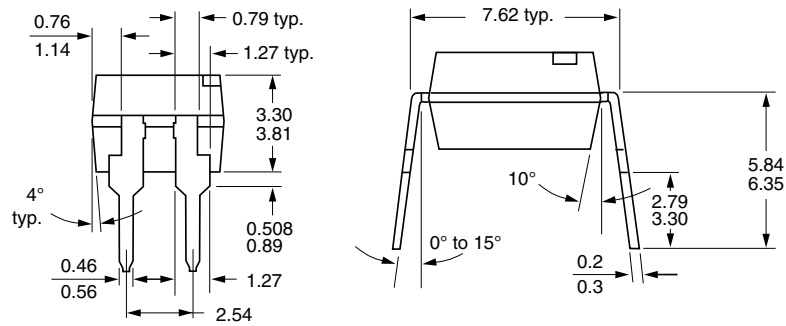
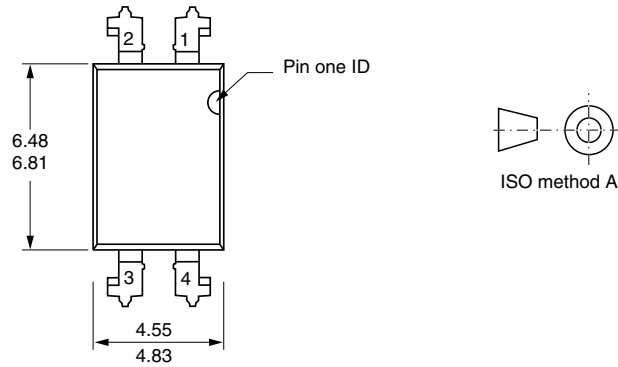


Fig. 8 - Permissible Power Dissipation vs. Temperature

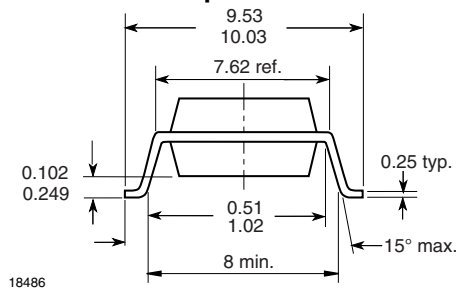


## PACKAGE DIMENSIONS in inches (millimeters)



i178027

### Option 9



18486



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